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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/080,913	02/21/2002	Luu Thanh Nguyen	NSC1P131X1	1176
22434	7590	07/27/2004	EXAMINER	
BEYER WEAVER & THOMAS LLP			FARAHANI, DANA	
P.O. BOX 778			ART UNIT	
BERKELEY, CA 94704-0778			PAPER NUMBER	
			2814	

DATE MAILED: 07/27/2004

Please find below and/or attached an Office communication concerning this application or proceeding.

Office Action Summary	Application No. 10/080,913	Applicant(s) NGUYEN ET AL.	
	Examiner Dana Farahani	Art Unit 2814	

-- The MAILING DATE of this communication appears on the cover sheet with the correspondence address --

Period for Reply

A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) FROM THE MAILING DATE OF THIS COMMUNICATION.

- Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.
- If the period for reply specified above is less than thirty (30) days, a reply within the statutory minimum of thirty (30) days will be considered timely.
- If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.
- Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).

Status

- 1) ☒ Responsive to communication(s) filed on 19 May 2004.
- 2a) ☐ This action is **FINAL**. 2b) ☒ This action is non-final.
- 3) ☐ Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under *Ex parte Quayle*, 1935 C.D. 11, 453 O.G. 213.

Disposition of Claims

- 4) ☒ Claim(s) 19-43 is/are pending in the application.
- 4a) Of the above claim(s) _____ is/are withdrawn from consideration.
- 5) ☐ Claim(s) _____ is/are allowed.
- 6) ☒ Claim(s) 19-43 is/are rejected.
- 7) ☐ Claim(s) _____ is/are objected to.
- 8) ☐ Claim(s) _____ are subject to restriction and/or election requirement.

Application Papers

- 9) ☐ The specification is objected to by the Examiner.
- 10) ☐ The drawing(s) filed on _____ is/are: a) ☐ accepted or b) ☐ objected to by the Examiner.
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).
Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).
- 11) ☐ The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.

Priority under 35 U.S.C. § 119

- 12) ☐ Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).
- a) ☐ All b) ☐ Some * c) ☐ None of:
1. ☐ Certified copies of the priority documents have been received.
 2. ☐ Certified copies of the priority documents have been received in Application No. _____.
 3. ☐ Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).

* See the attached detailed Office action for a list of the certified copies not received.

Attachment(s)

- | | |
|------------------------------------------------------------------------------------------------------------------------|-----------------------------------------------------------------------------------------|
| 1) <input type="checkbox"/> Notice of References Cited (PTO-892) | 4) <input type="checkbox"/> Interview Summary (PTO-413)
Paper No(s)/Mail Date. _____ |
| 2) <input type="checkbox"/> Notice of Draftsperson's Patent Drawing Review (PTO-948) | 5) <input type="checkbox"/> Notice of Informal Patent Application (PTO-152) |
| 3) <input type="checkbox"/> Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08)
Paper No(s)/Mail Date _____ | 6) <input type="checkbox"/> Other: _____ |

DETAILED ACTION

Claim Rejections - 35 USC § 102

1. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless –

(e) the invention was described in a patent granted on an application for patent by another filed in the United States before the invention thereof by the applicant for patent, or on an international application by another who has fulfilled the requirements of paragraphs (1), (2), and (4) of section 371(c) of this title before the invention thereof by the applicant for patent.

The changes made to 35 U.S.C. 102(e) by the American Inventors Protection Act of 1999 (AIPA) and the Intellectual Property and High Technology Technical Amendments Act of 2002 do not apply when the reference is a U.S. patent resulting directly or indirectly from an international application filed before November 29, 2000. Therefore, the prior art date of the reference is determined under 35 U.S.C. 102(e) prior to the amendment by the AIPA (pre-AIPA 35 U.S.C. 102(e)).

2. Claims 19, 22, 24, and 26-28 are rejected under 35 U.S.C. 102(e) as being anticipated by Nishiguchi et al., hereinafter Nishiguchi (U.S. Patent 5,214,308).

Regarding claims 19, 22, 24, 28 and 28, Nishiguchi discloses in figures 2 and 3 an apparatus comprising a flip chip integrated circuit 1 having bond pads with solder bumps 2 formed directly on an active surface of the flip chip; and a layer of an underfill layer (not shown, see column 3, lines 45-52) is formed on the active surface, and around the bumps of the flip chip integrated circuit.

Regarding claim 26, the substrate 3 has a plurality of contact pads 5, which connect the flip chip to the substrate.

Claim Rejections - 35 USC § 103

3. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negated by the manner in which the invention was made.

4. Claim 23 is rejected under 35 U.S.C. 103(a) as being unpatentable over Nishiguchi.

Nishiguchi discloses the limitation in claim 23, as discussed above, except for the relative dimensions of the bumps and the adhesive. Note that the specification contains no disclosure of either the critical nature of the claimed dimensions of any unexpected results arising therefrom. Where patentability is said to be based upon particular chosen dimensions or upon another variable recited in a claim, the Applicant must show that the chosen dimensions are critical. In re Woodruff, 919 F.2d 1575, 16 USPQ 2d 1934, 1936 (Fed. Cir. 1990). It would have been obvious to one of ordinary skill in the art at the time the invention was made to make the contact bumps smaller or larger according to a specific application.

5. Claims 20 and 25 are rejected under 35 U.S.C. 103(a) as being unpatentable over Nishiguchi, as applied to claim 19 above, and further in view of Kato (U.S. Patent 6,486,562).

Nishiguchi discloses the limitation in claims 19 and 20, as discussed above, except for the adhesive being an epoxy resin.

Kato discloses at column 2, lines 10-15, that epoxy resin is used to increase mechanical coupling between a substrate and a flip chip. Therefore, it would have been obvious to one of ordinary skill in the art at the time of the invention to use epoxy resin as the adhesive in

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Nishiguchi structure in order to enhance mechanical coupling between the substrate and the flip chip.

6. Claim 21 is rejected under 35 U.S.C. 103(a) as being unpatentable over Nishiguchi, as applied to claim 19 above, and further in view of Morihara (U.S. Patent 5,495,439).

Nishiguchi discloses the limitations in claims 19 and 21, as discussed above, except for coefficient of thermal expansion of the substrate is substantially similar to the adhesive.

Morihara discloses a device package wherein an adhesive layer has coefficient of thermal expansion same as a substrate in which it is located. Therefore, it would have been obvious to one of ordinary skill in the art at the time of the invention to make the device in Schuelle such that coefficient of thermal expansion of the adhesive is same as the substrate to reduce stress related failures due to coefficient of thermal expansion mismatch between the substrate and the adhesive layer.

7. Claims 29-31 are rejected under 35 U.S.C. 103(a) as being unpatentable over Nishiguchi.

Nishiguchi discloses the limitations in the claims, as discussed above, except for the range of coefficient of thermal expansion of the adhesive, and other properties of the adhesive mentioned in those claims. It would have been obvious to one of ordinary skill in the art at the time of the invention to choose appropriate range of coefficient of thermal expansion for a particular application, since it has been held that where the general conditions of a claim are disclosed in the prior art, discovering the optimum or working ranges involves only routine skill in the art. *In re Aller*, 105 USPQ 233.

8. Claims 32-34 are rejected under 35 U.S.C. 103(a) as being unpatentable over Nishiguchi, as applied to claim 19 above, and further in view of Chiu et al., hereinafter Chiu (U.S. Patent 6,391,683).

Nishiguchi discloses the limitations in those claims, as discussed above, except for a dam around the underfill adhesive and a solder, or fluxing material on the substrate. Chiu discloses in figure 3C dam 111 around resin 141, and resin 141 is on substrate 110. Therefore, it would have been obvious to one of ordinary skill in the art at the time of the invention to use a resin material on the substrate of Nishiguchi, and further form a dam around it in order to support the contacts 34 of the Nishiguchi structure, while preventing the material from flowing to peripheral areas of the substrate.

9. Claims 35, 36, and 39, are rejected under 35 U.S.C. 103(a) as being unpatentable over Nishiguchi in view of Holzapfel et al., hereinafter Holzapfel (U.S. Patent 5,872,633).

Nishiguchi discloses the limitations in the claims, as discussed above, except for a plurality of die.

Holzapfel discloses in figure 6 a semiconductor device with a plurality of die 406.

Therefore, it would have been obvious to one of ordinary skill in the art at the time of the invention to use a plurality of die in the Nishiguchi reference in order to make an array of chip packages to be used in various applications, as this is common in the semiconductor manufacturing industry.

10. Claim 37 is rejected under 35 U.S.C. 103(a) as being unpatentable over Nishiguchi in view Holzapfel.

Nishiguchi and Holzapfel disclose the limitation in claim 35, as discussed above, except for the relative dimensions of the bumps and the adhesive. Note that the specification contains no disclosure of either the critical nature of the claimed dimensions of any unexpected results arising therefrom. Where patentability is said to be based upon particular chosen dimensions or upon another variable recited in a claim, the Applicant must show that the chosen dimensions are critical. In re Woodruff, 919 F.2d 1575, 16 USPQ 2d 1934, 1936 (Fed. Cir. 1990). It would have been obvious to one of ordinary skill in the art at the time the invention was made to make the contact bumps smaller or larger according to a specific application.

11. Claim 38 is rejected under 35 U.S.C. 103(a) as being unpatentable over Nishiguchi in view Holzapfel, as applied to claim 35 above, and further in view of Kato (U.S. Patent 6,486,562).

Nishiguchi and Holzapfel disclose the limitation in the claim, as discussed above, except for the adhesive being an epoxy resin.

Kato discloses at column 2, lines 10-15, that epoxy resin is used to increase mechanical coupling between a substrate and a flip chip. Therefore, it would have been obvious to one of ordinary skill in the art at the time of the invention to use epoxy resin as the adhesive in Nishiguchi structure in order to enhance mechanical coupling between the substrate and the flip chip.

12. Claims 40-42 are rejected under 35 U.S.C. 103(a) as being unpatentable over Nishiguchi in view Holzapfel.

Nishiguchi in view Holzapfel renders obvious the limitations in the claims, except for the range of coefficient of thermal expansion of the adhesive, and other properties of the adhesive

mentioned in those claims. It would have been obvious to one of ordinary skill in the art at the time of the invention to choose appropriate range of coefficient of thermal expansion for a particular application, since it has been held that where the general conditions of a claim are disclosed in the prior art, discovering the optimum or working ranges involves only routine skill in the art. *In re Aller*, 105 USPQ 233.

13. Claim 43 is rejected under 35 U.S.C. 103(a) as being unpatentable over Nishiguchi in view Holzapfel, as applied to claim 35 above, and further in view of Chiu et al., hereinafter Chiu (U.S. Patent 6,391,683).

Nishiguchi in view Holzapfel renders obvious the limitations in those claims, as discussed above, except for a dam around the underfill adhesive and a solder, or fluxing material on the substrate.

Chiu discloses in figure 3C dam 111 around resin 141, and resin 141 is on substrate 110. Therefore, it would have been obvious to one of ordinary skill in the art at the time of the invention to use a resin material on the substrate of Nishiguchi, and further form a dam around it in order to support the contacts 34 of the Nishiguchi structure, while preventing the material from flowing to peripheral areas of the substrate.

Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Dana Farahani whose telephone number is (571)272-1706. The examiner can normally be reached on M-F 9:00AM - 6:00PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Wael M Fahmy can be reached on (571)272-1705. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see <http://pair-direct.uspto.gov>. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

D. Farahani



LONG PHAM
PRIMARY EXAMINER